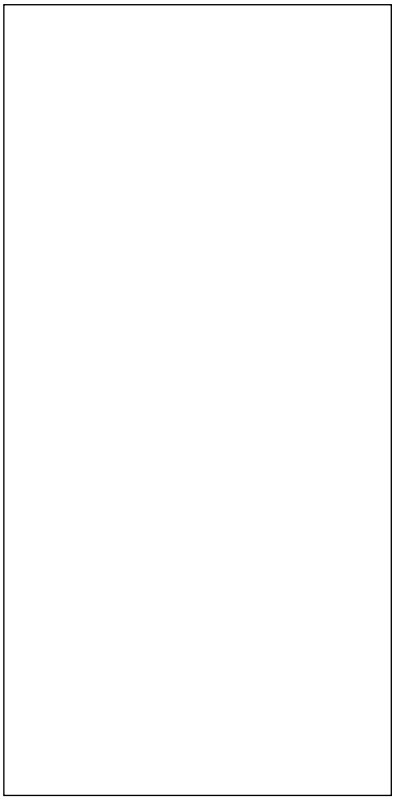
JST60T-1200BW 60A TRIAC

Rev.A.1.0

DESCRIPTION:

The JST60T-1200BW triac is suitable for general purpose AC switching. It can be used as an ON/OFF function in applications such as heating regulation, induction motor starting circuits, for phase control operation in light dimmers, motor speed controllers. JST60T-1200BW snubberless triac is especially recommended for use on inductive loads. By using a DBC, JST60T-1200BW provides a rated insulation voltage of 2500 VRMS, complying with UL standards (File ref: E252906). Package TG-C is RoHS compliant.



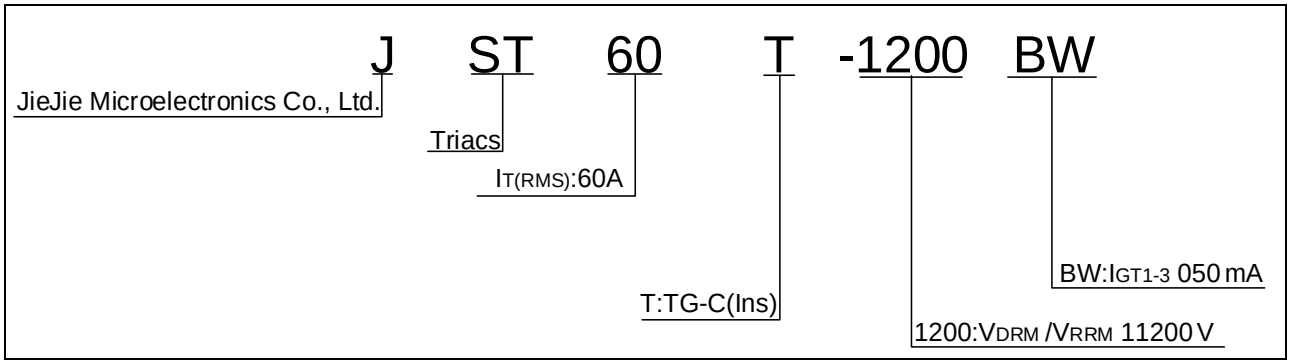
MAIN FEATURES

Symbol	Value	Unit
$I_{T(RMS)}$	60	A
V_{DRM} /V_{RRM}	1200	V
I_{GT} / /	50/50/50	mA

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Storage junction temperature range	T_{stg}	-40-150	
Operating junction temperature range	T_j	-40-125	
Repetitive peak off-state voltage (T_j=25)	V_{DRM}	1200	V
Repetitive peak reverse voltage (T_j=25)	V_{RRM}	1200	V
RMS on-state current (T_C 094)	$I_{T(RMS)}$	60	A
Non repetitive surge peak on-state current (full cycle , t_p=20ms , T_j=25)	I_{TSM}	600	A
Non repetitive surge peak on-state current (full cycle , t_p=16.6ms , T_j=25)		660	
I^2t value for fusing (t_p=10ms , T_j=25)	I^2t	1800	A^2s
Critical rate of rise of on-state current (I_G=2× I_{GT} , f=100Hz , T_j=125)	dI/dt	100	A s
Peak gate current (t_p=20 s , T_j=125)	I_{GM}	10	A
Average gate power dissipation (T_j=125)	$P_{G(AV)}$	0.5	W

ORDERING INFORMATION



MARKING

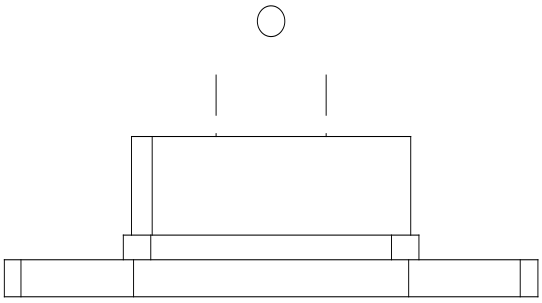
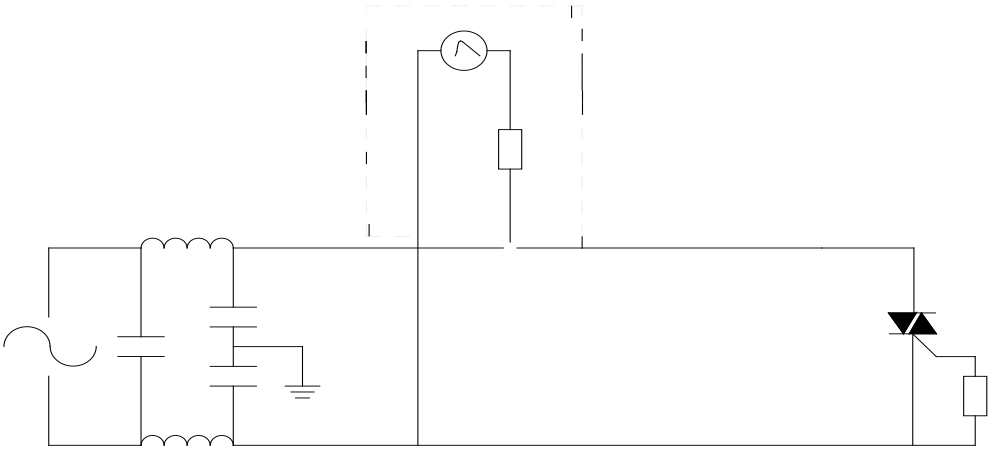


FIG.1: Maximum power dissipation versus RMS on-state current

FIG.2:

FIG.7 ÖTest circuit for inductive and resistive loads to IEC-61000-4-5 standards



PACKAGE MECHANICAL DATA



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